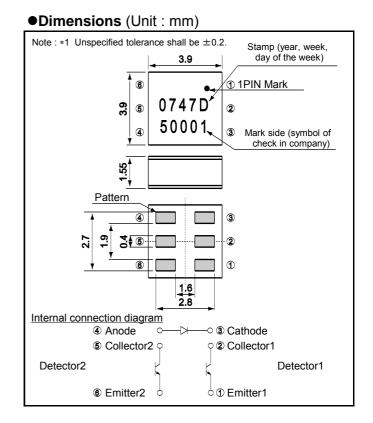
Applications

- DSCs
- DVCs
- Projectors

Features

- 1) Surface mount
- 2) Optical
- 3) 4-way detection possible



•Absolute maximum ratings (Ta = 25°C)

F	Parameter	Symbol	Value	Unit
Input (Infrared light emitting diode)	Forward current	١ _F	35	mA
	Reverse voltage	V _R	5	V
	Power dissipation	P _D	80	mW
	Collector-emitter voltage	V _{CEO}	30	V
Output	Emitter-collector voltage	V _{ECO}	4.5	V
(Phototransistor)	Collector current	Ι _C	30	mA
	Collector dissipation	P _C	80	mW
Operating temperature	9	T _{opr}	–25 to +85	°C
Storage temperature		T _{stg}	-30 to +85	°C

•Electrical and optical characteristics (Ta = 25°C)

1) Input characteristics

Parameter	Symbol	Conditions		Values		Unit V	
Faranieler	Symbol	Conditions	ConditionsMin.Typ.MaxmA-1.351.6		Max.	Onic	
Forward voltage	V _F	I _F =5mA	-	1.35	1.6	V	
Reverse current	I _R	V _R =5V	-	-	10	μA	
Peak light emitting wavelength λ_p		I _F =5mA	-	850	-	nm	

* Non-coherent Infrared light emitting diode used.

2) Output characteristics

Parameter	Symbol	Conditions		Values		Unit
Faranieler	Symbol	Conditions	Min. Typ. Max	Max.	Unit	
Dark current	I _{CED}	V _{CE} =10V	-	-	0.5	μA
Peak sensitivity wavelength	λ_p		-	800	-	nm

3) Transfer characteristics

Parameter		Symbol	Conditions	Values			Linit
		Symbol	Symbol Conditions -		Тур.	Max.	Unit
Collector current		I _C	V _{CE} =5V I _F =5mA	150	-	-	
Leak current		l _{leak}	V _{CE} =5V I _F =5mA	-	-	12	μΑ
Collector-emitter saturation voltage		V _{CE(sat)}	I _F =20mA I _C =0.1mA	-	-	0.4	V
Response time	Rise time	tr	V _{CC} =5V, I _F =20mA	-	10	-	
	Fall time	tf	R _L =100Ω	-	10	-	μS

•Electrical and optical characteristic curves

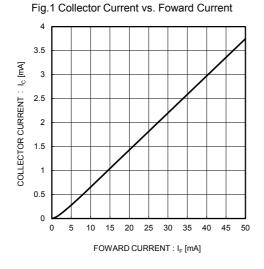


Fig.3 Forward Current vs. Foward Voltage

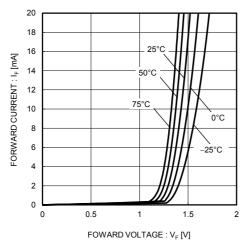
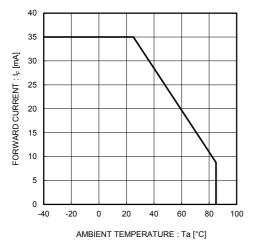


Fig.5 Forward Current Fall Off



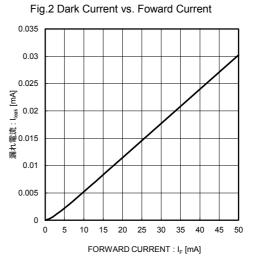


Fig.4 Relative Output vs. Ambient Temperature

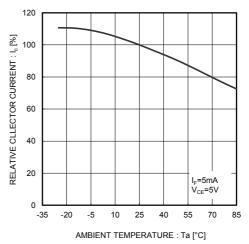
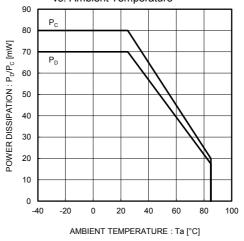


Fig.6 Power Dissipation/Collector Power Dissipation vs. Ambient Temperature



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